

BCR12CM-16LB

800V - 12A - Triac

Medium Power Use

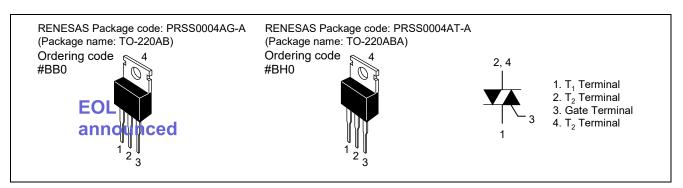
Features

Outline

- I_{T (RMS)} : 12 A
- V_{DRM} : 800 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 30 mA

• Tj: 150°C

- Non-insulated Type
- Planar Passivation Type



Application

Power supply, motor control, heater control and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		16	
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	800	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	960	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	12	A	Commercial frequency, sine full wave 360° conduction, Tc = 123°C ^{Note3}
Surge on-state current	I _{TSM}	120	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
l ² t for fusion	l ² t	60	A²s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	Рдм	5	W	
Average gate power dissipation	P _G (AV)	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	lgм	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	

Rev.3.00

Feb. 1, 2019

Data Sheet

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	IDRM	—	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	—	1.6	V	Tc = 25° C, I_{TM} = 20 A, instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	Vfgti	—	—	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	V _{RGTI}	—	—	1.5	V	R _G = 330 Ω
	III	Vrgtiii	_	—	1.5	V	
Gate trigger current ^{Note2}	Ι	IFGTI	—	—	30	mA	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	IRGTI	—	—	30	mA	R _G = 330 Ω
	III	IRGTIII	—	—	30	mA	
Gate non-trigger voltage		Vgd	0.2	—	_	V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	—	_	V	Тј = 150°С, V _D = 1/2 V _{DRM}
Thermal resistance		Rth (j-c)	_	—	1.8	°C/W	Junction to case ^{Note3 Note4}
Critical-rate of rise of off-state (dv		(dv/dt)c	10			V/μs	Tj = 125°C
commutation voltage ^{Note5}			1	_	_	V/μs	Tj = 150°C

Notes: 1. Gate open.

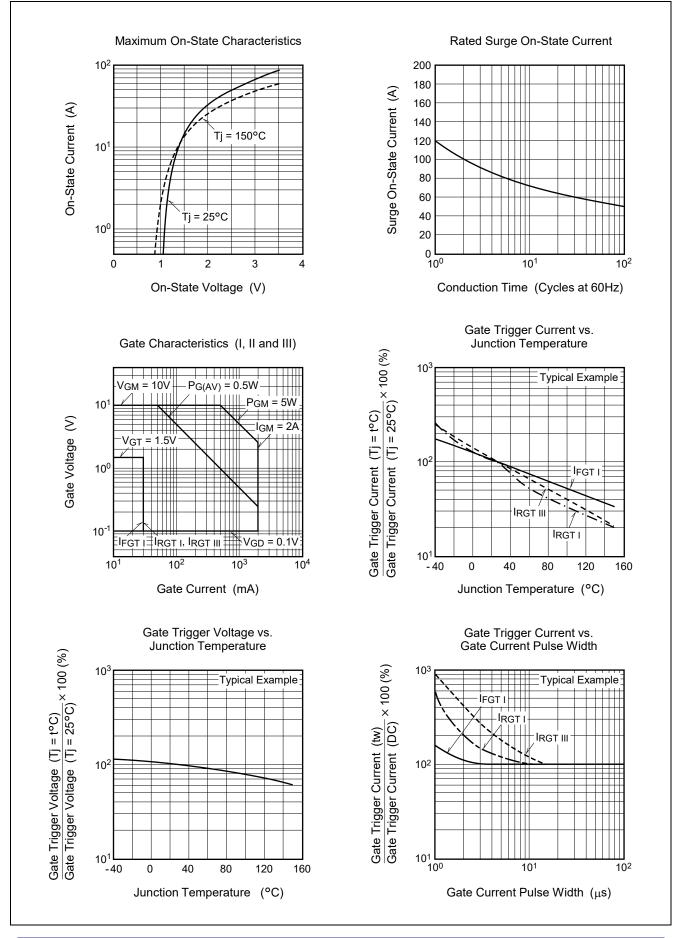
2. Measurement using the gate trigger characteristics measurement circuit.

- 3. Case temperature is measured at the $T_2 \mbox{ tab } 1.5\mbox{ mm}$ away from the molded case.
- 4. The contact thermal resistance $R_{th(c\text{-}f)}$ in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

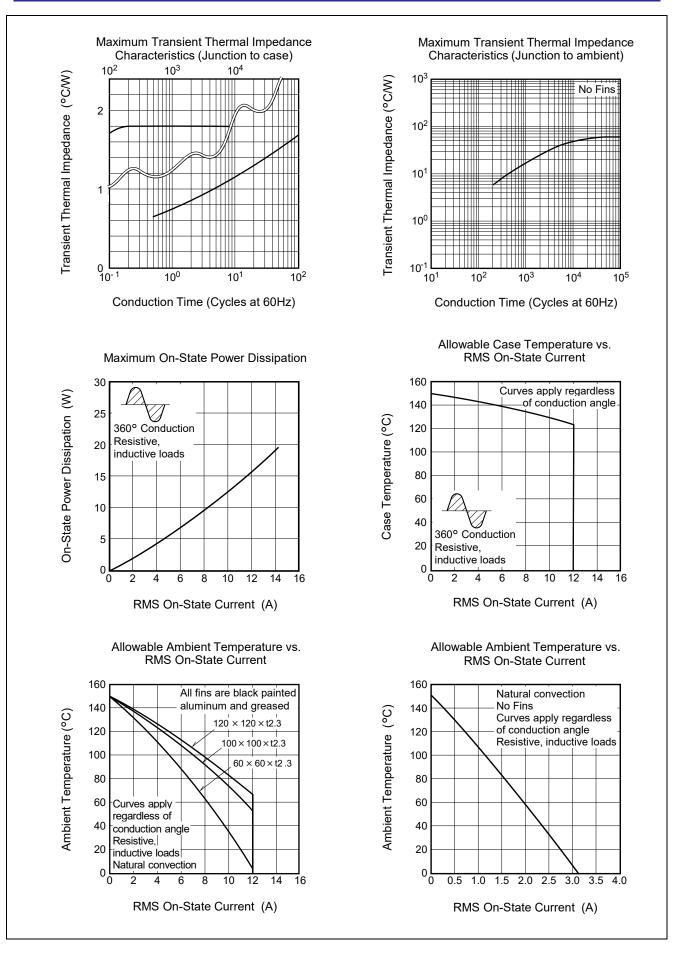
Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature Tj = 125°C/150°C Rate of decay of on-state commutating current (di/dt)c = -6 A/ms Peak off-state voltage V_D = 400 V 	Supply Voltage Main Current Main Voltage (dv/dt)c Time Main Voltage VD



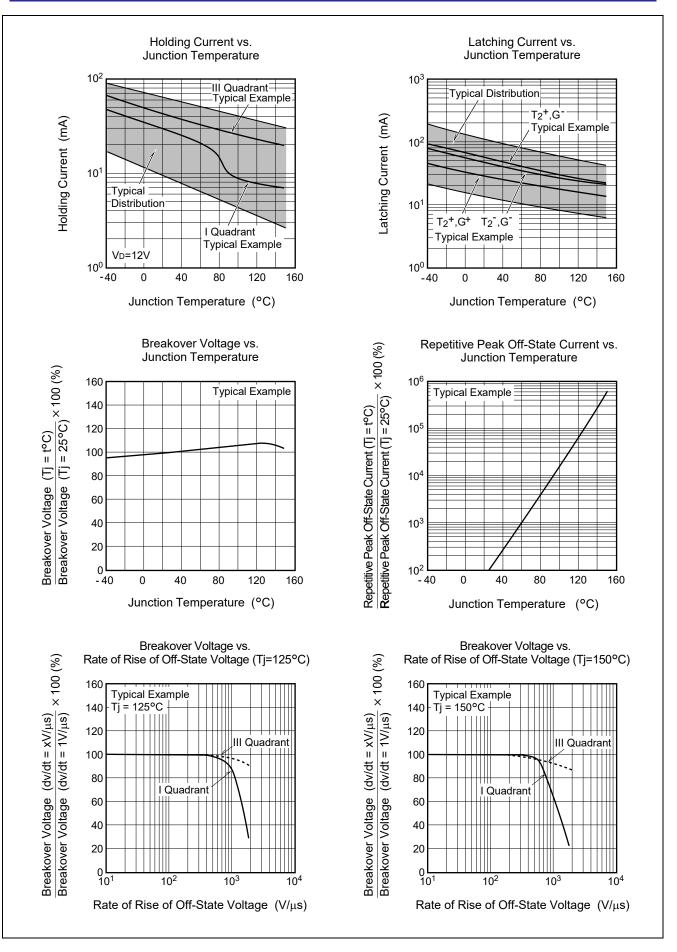
Performance Curves



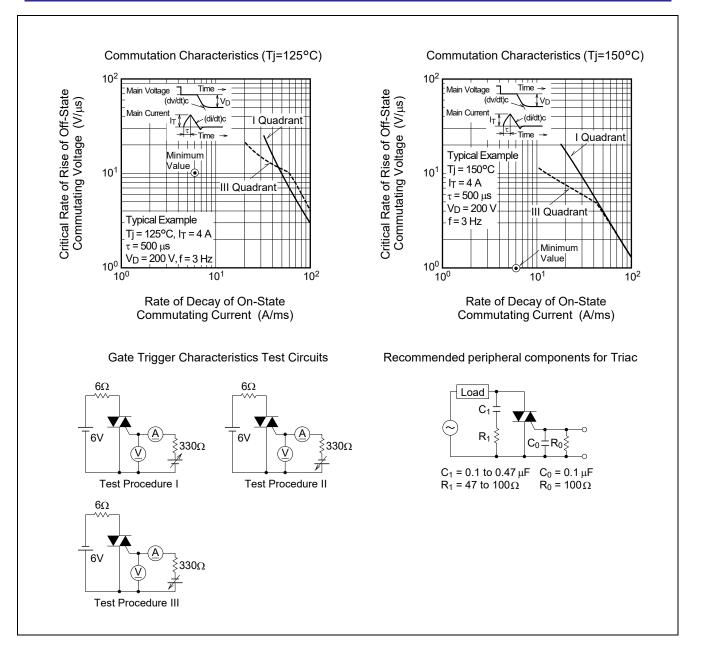




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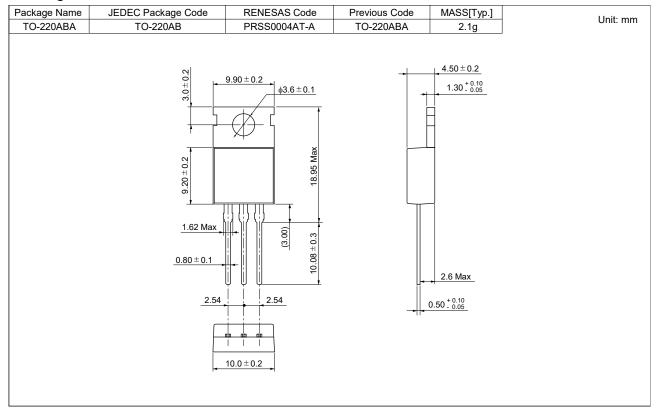




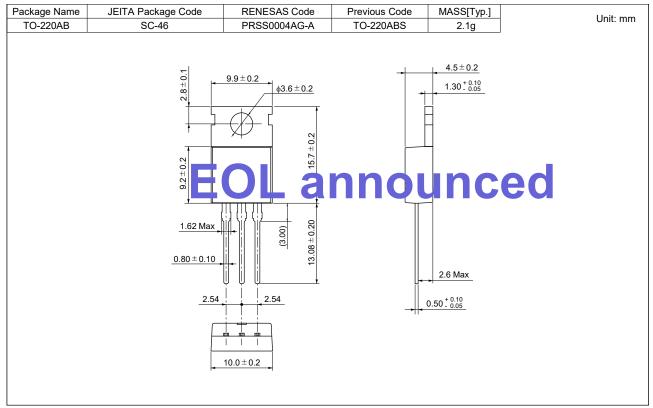


Package Dimensions

Ordering code: #BH0



Ordering code: #BB0





Ordering Information

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR12CM-16LB#BH0	TO-220ABA	50 pcs./ tube	Straight type	Mass Production
BCR12CM-16LB#BB0	TO-220ABS	50 pcs./ tube	Straight type	EOL announced

Notes: 6. Please confirm the specification about the shipping in detail.

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(Rev.4.0-1 November 2017)



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